



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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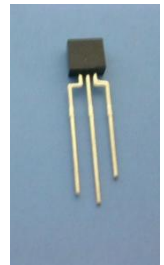
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



### Side Face Silicon Phototransistor EAPLP04RRAA3

#### Features

- Fast response time
- High photo sensitivity
- Pb free
- This product itself will remain within RoHS compliant version.



#### Description

- EAPLP04RRAA3 is a high speed and high sensitive dual phototransistor molded in a black plastic package with plat side view.
- The device is spectrally matched with IR emitters.

#### Applications

- Mouse
- Optoelectronic Switch
- Photo Interrupter

## Device Selection Guide

Chip Materials	Lens Color
Si	Black

## Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Unit
Collector-Emitter Voltage	$V_{CEO}$	30	V
Emitter-Collector-Voltage	$V_{ECO}$	5	V
Collector Current	$I_C$	20	mA
Operating Temperature	$T_{opr}$	-25 ~ +85°C	°C
Storage Temperature	$T_{stg}$	-40 ~ +85°C	°C
Lead Soldering Temperature(*1)	$T_{sol}$	260	°C
Power Dissipation at (or below) 25°C Free Air Temperature	$P_D$	75	mW

**Notes:** \*1:Soldering time  $\leq$  5 seconds.

**Electro-Optical Characteristics (Ta=25°C)**

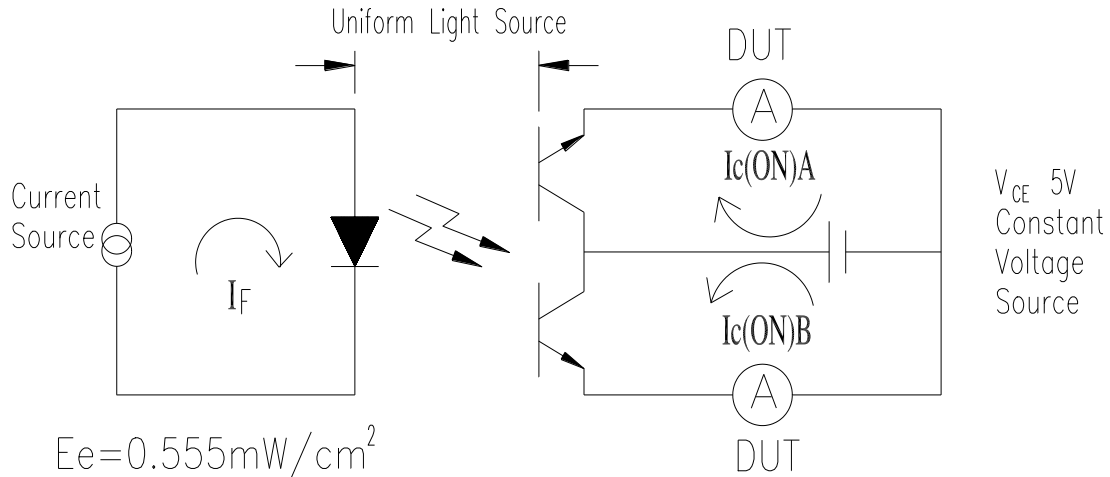
Parameter	Symbol	Condition	Min	Typ	Max	Unit
Collector – Emitter Breakdown Voltage	$BV_{CEO}$	$I_C=100\mu A$ $E_e=0mW/cm^2$	30	---	---	V
Emitter-Collector Breakdown Voltage	$BV_{ECO}$	$I_E=100\mu A$ $E_e=0mW/cm^2$	5	---	---	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=2mA$ $E_e=1mW/cm^2$	---	---	0.4	V
Rise Time	$t_r$	$V_{CE}=5V$ $I_C=1mA$ $R_L=1000\Omega$	---	15	---	$\mu S$
Fall Time	$t_f$		---	15	---	
Collector Dark Current	$I_{CEO}$	$E_e=0mW/cm^2$ $V_{CE}=20V$	---	---	100	nA
On State Collector Current	$I_{C(on)}$	$V_{CE}=5V$ , $E_e=0.555mW/cm^2$	129	---	1085	$\mu A$
Wavelength of Peak Sensitivity	$\lambda_p$	---	---	940	---	nm
Rang of Spectral Bandwidth	$\lambda_{0.5}$	---	760	---	1100	nm

**Test Method For On State Collector Current :**

Condition :  $E_e=0.555\text{mW/cm}^2$ ,  $V_{CE}=5\text{V}$

Test Item : Collector Current [ $I_{C(ON)}$ ]

Unit :  $\mu\text{A}$



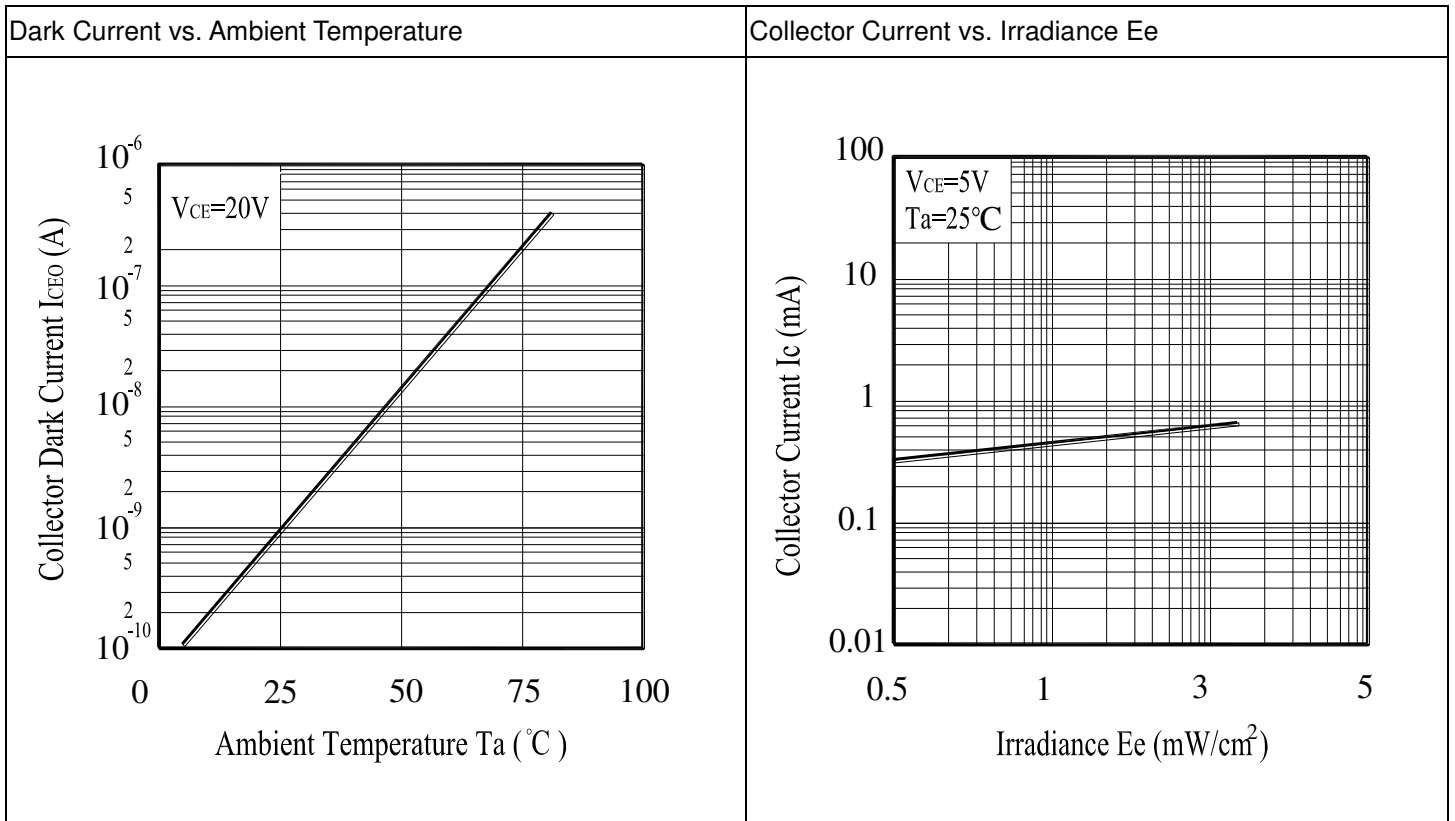
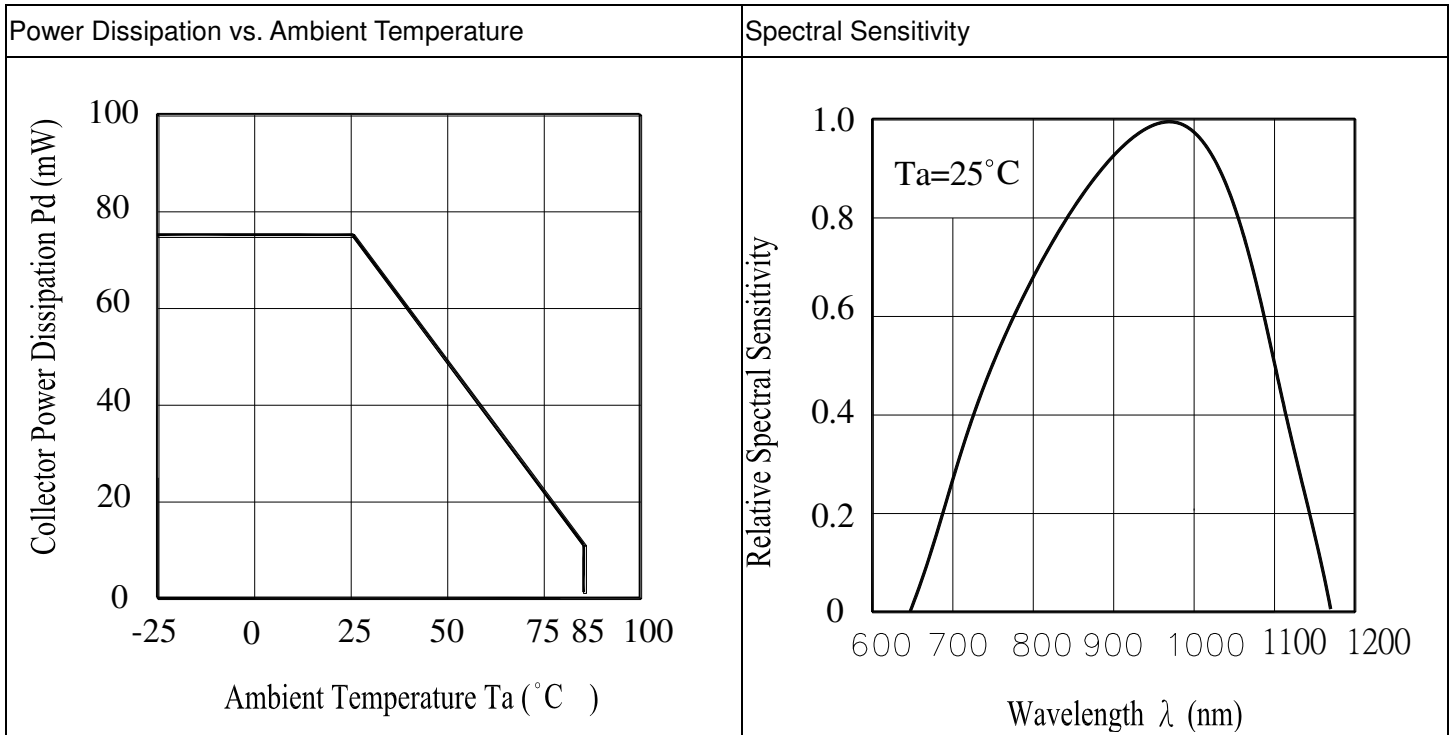
**To Distinguish Intensity:**

Condition:  $V_{CE}=5\text{V}$   $E_e=0.555\text{mW/cm}^2$

Ranks

Ranks	Symbol	Min	Typ	Max	Unit	Test Condition
A1	$I_{C(ON)}$	129	---	226	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$
A2	$I_{C(ON)}$	195	---	306	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$
A3	$I_{C(ON)}$	262	---	380	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$
A4	$I_{C(ON)}$	330	---	461	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$
A5	$I_{C(ON)}$	398	---	544	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$
A6	$I_{C(ON)}$	468	---	625	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$
A7	$I_{C(ON)}$	536	---	703	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$
A8	$I_{C(ON)}$	604	---	785	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$
A9	$I_{C(ON)}$	673	---	862	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$
A10	$I_{C(ON)}$	742	---	944	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$
A11	$I_{C(ON)}$	812	---	1018	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$
A12	$I_{C(ON)}$	882	---	1085	$\mu\text{A}$	$E_e=0.555\text{mW/c m}^2$ $V_{CE}=5\text{V}$

**Typical Electro-Optical Characteristics Curves**

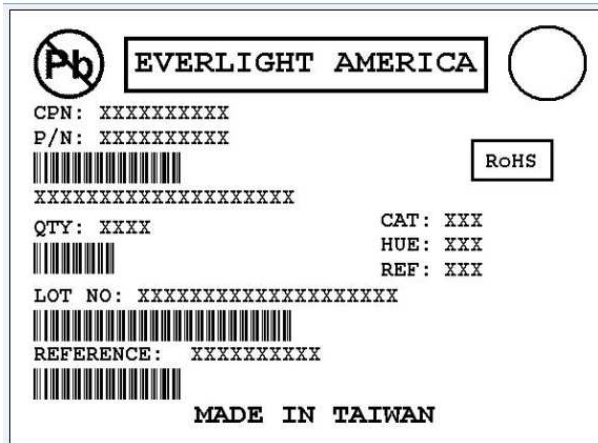




### Packing Quantity Specification

1. 1000Pcs/1Bag , 8Bags/1Box
2. 10Boxes/1Carton

### Label Form Specification



- CPN: Customer's Product Number
- P/N: Product Number
- QTY: Packing Quantity
- CAT: Luminous Intensity Rank
- HUE: Dom. Wavelength Rank
- REF: Forward Voltage Rank
- LOT No: Lot Number
- X: Month
- Reference: Identify Label Number

### Notes

1. Above specification may be changed without notice. EVERLIGHT Americas will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT Americas assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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